## NSN 5961-01-175-8456

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-175-8456 **Inclosure Material:** Metal **Overall Length:** 0.185 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.370 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-99 **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 45.0 breakdown voltage, collector-to-base, emitter open all transistor and 45.0 breakdown voltage, collector-to-emitter, base open all transistor and 45.0 collector supply voltage all transistor and 45.0 emitter supply voltage all transistor and 5.0 emitter to base voltage, static, collector open all transistor **Current Rating Per Characteristic:** 25.00 milliamperes source cutoff current all transistor and 25.00 milliamperes source cutoff current blank all transistor **Power Rating Per Characteristic:** 500.0 milliwatts any acceptable preset all transistor **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** All transistor junction pattern arrangement: npn **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

No Fiig:

A110a0